

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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1.6X0.8mm INFRARED EMITTING DIODE



### www.SunLEDusa.com

### www.ouneebusa.com

### **Features**

• Long life and robust package

• Standard Package: 2,000pcs/ Reel

 $\bullet$  MSL (Moisture Sensitivity Level): 3

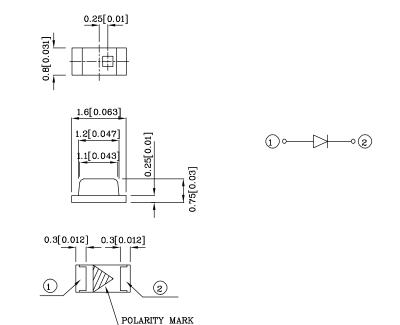
• RoHS compliant

Feb 09,2017





### **Package Schematics**



#### Notes

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is  $\pm 0.1 (0.004")$  unless otherwise noted.
- 3. Specifications are subject to change without notice.

Absolute Maximum Ratings (T <sub>A</sub> =25°C)		Infrared (GaAs)	Unit	
Reverse Voltage	$V_{\rm R}$	5	V	
Forward Current	$I_{\mathrm{F}}$	50	mA	
Forward Current (Peak) 1/100 Duty Cycle 10us Pulse Width	$i_{\mathrm{FS}}$	1200	mA	
Power Dissipation	$P_{D}$	80	mW	
Operating Temperature	$T_{\rm A}$	-40 ~ +85	°C	
Storage Temperature	Tstg	-40 ~ +85		

A Relative Humidity between 40% and 60% is recommended in ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)

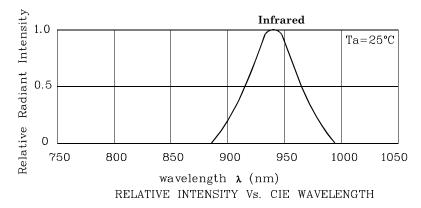
Operating Characteristics $(T_A=25^{\circ}C)$	Infrared (GaAs)	Unit	
Forward Voltage (Typ.) (I <sub>F</sub> =20mA)	$V_{\mathrm{F}}$	1.2	V
Forward Voltage (Max.) (I <sub>F</sub> =20mA)	$V_{\mathrm{F}}$	1.6	V
Reverse Current (Max.) $(V_R=5V)$	$I_{\mathrm{R}}$	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I <sub>F</sub> =20mA)	λΡ	940*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =20mA)	$\triangle \lambda$	50	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	С	90	pF

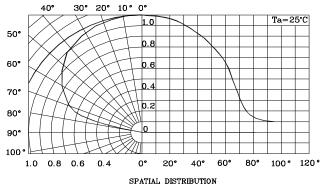
Part Number	Emitting Material	Lens-color	Radiant Intensity CIE127-2007* (Po=mW/sr) @20mA		Wavelength CIE127-2007* nm λΡ	Viewing Angle 20 1/2
			min.	typ.		
XZTNI53W-1	GaAs	Water Clear	1.2 0.8*	2.8 1.8*	940*	150°

 $<sup>{}^{*}</sup>$ Radiant Intensity value and wavelength are in accordance with CIE127-2007 standards.

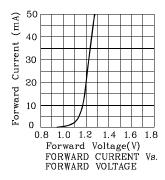


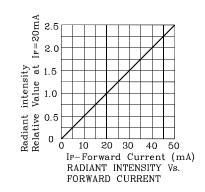


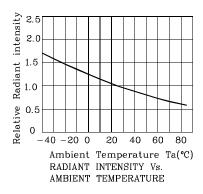




### **❖** Infrared

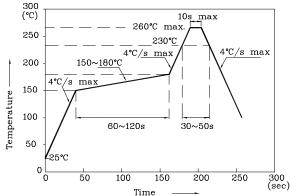






# LED is recommended for reflow soldering and soldering profile is shown below.

Reflow Soldering Profile for SMD Products (Pb-Free Components)



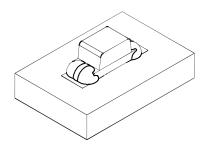
### Notes:

- 1. Maximum soldering temperature should not exceed 260°C  $\,$
- 2. Recommended reflow temperature: 245°C-260°C
- 3. Do not put stress to the epoxy resin during high temperatures conditions

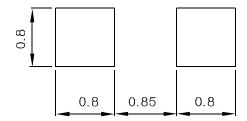




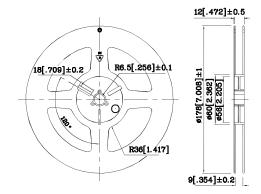
# ♦ The device has a single mounting surface. The device must be mounted according to the specifications.



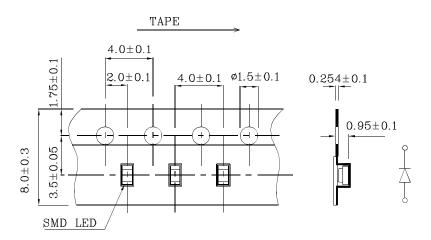
## **♦** Recommended Soldering Pattern (Units: mm; Tolerance: ± 0.1)



### **❖** Reel Dimension



### **❖** Tape Specification (Units:mm)



### Remarks:

If special sorting is required (e.g. binning based on forward voltage or radiant intensity / luminous flux), the typical accuracy of the sorting process is as follows:

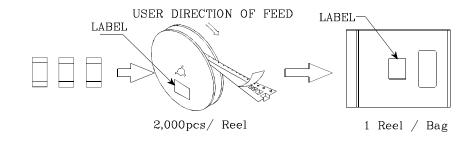
- 1. Radiant Intensity / Luminous Flux: +/-15%
- 2. Forward Voltage: +/-0.1V

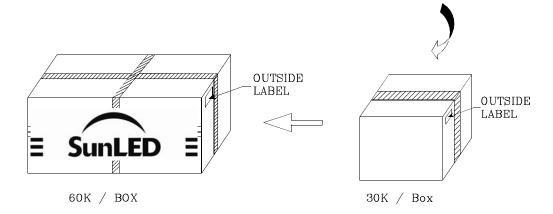
Note: Accuracy may depend on the sorting parameters

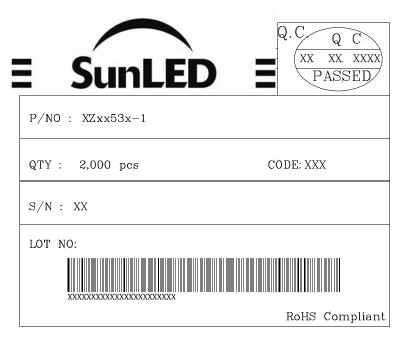


### 1.6X0.8mm INFRARED EMITTING DIODE

### PACKING & LABEL SPECIFICATIONS







### TERMS OF USE

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- 6. Additional technical notes are available at <a href="http://www.SunLEDusa.com/TechnicalNotes.asp">http://www.SunLEDusa.com/TechnicalNotes.asp</a>

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